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Inclosure Materia	l:
Metal	
Overall Length:	
0.405 inches	
Function For Whi	ch Designed:
Voltage regulator	
Mounting Facility	Quantity:
1	
Joint Electronic [	Device Engineering Council/jedec/case Outline Designation:
Do-4	
Mounting Method	:
Threaded stud	
Features Provide	d:
Hermetically seale	d case
Overall Width Ac	ross Flats:
0.505 inches	
Thread Size:	
0.190 inches	
Semiconductor N	laterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
51.0 regulator vo	tage
Current Rating Po	er Characteristic:
50.00 milliamperes	source cutoff current horsepower metric
Power Rating Per	Characteristic:
10.0 watts small-s	gnal input power, common-collector preset
Maximum Operat	ing Tempurature Per Measurement Point:
175.0 degrees cels	sius junction
Test Data Docum	ent:
81349-mil-s-19500	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes of	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series De	signator:
Unf	
Terminal Type Ar	d Quantity:
1 tab, solder lug a	nd 1 threaded stud
Specification Dat	a:
81349-mil-s-19500	/124 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	

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